

Magneto-optical properties of ZnO:Co nanocrystalline films

Hoang L.H., Khoi N.T., Hai N.H., Pacuski W., Yang I.-S.

Faculty of Physics, Hanoi National University of Education, 136 Xuan Thuy, Cau Giay, Hanoi, Viet Nam;
Center for Materials Science, Hanoi University of Science, Vietnam National University, Hanoi, Viet Nam;
Institute of Experimental Physics, Warsaw University, Poland; Division of Nano-Sciences, Department of
Physics, Ewha Woman University, Seoul 120-750

Abstract: Co doped ZnO films were synthesized from the precursors $\text{Zn}(\text{CH}_3\text{COO})_2 \cdot 2\text{H}_2\text{O}$ and $\text{Co}(\text{CH}_3\text{COO})_2 \cdot 4\text{H}_2\text{O}$ by using a "High Voltage Spray Pyrolysis" technique. The physical properties of the prepared films were characterized by using scanning electron microscopy (SEM), X-ray diffraction (XRD) and physical property measurement system (PPMS) measurements. The films studied were of a wurtzite phase with grain sizes of about 20 nm. The 5 % Co-doped ZnO films exhibited ferromagnetic behavior at room temperature. The transmission and the optical magnetic circular dichroism (MCD) measurements confirmed that Co^{2+} was located at the tetrahedral sites of the ZnO wurtzite structure. MCD results showed that the observed ferromagnetism was less likely related to a carrier-induced mechanism.

Author Keywords: Diluted magnetic semiconductor; Ferromagnetism; Optical magnetic circular dichroism

Year: 2008

Source title: Journal of the Korean Physical Society

Volume: 52

Issue: 5

Page : 1621-1624

Cited by: 1

Link: Scopus Link

Correspondence Address: Hoang, L. H.; Faculty of Physics, Hanoi National University of Education, 136 Xuan Thuy, Cau Giay, Hanoi, Viet Nam; email: hoanglhsp@yahoo.com

ISSN: 3744884

Language of Original Document: English

Abbreviated Source Title: Journal of the Korean Physical Society

Document Type: Article

Source: Scopus

Authors with affiliations:

1. Hoang, L.H., Faculty of Physics, Hanoi National University of Education, 136 Xuan Thuy, Cau Giay, Hanoi, Viet Nam
2. Khoi, N.T., Faculty of Physics, Hanoi National University of Education, 136 Xuan Thuy, Cau Giay, Hanoi, Viet Nam
3. Hai, N.H., Center for Materials Science, Hanoi University of Science, Vietnam National University, Hanoi, Viet Nam
4. Pacuski, W., Institute of Experimental Physics, Warsaw University, Poland
5. Yang, I.-S., Division of Nano-Sciences, Department of Physics, Ewha Woman University, Seoul 120-750

References:

1. Wolf, S.A., (2000) J. Supercond, 13, p. 195
2. Ueda, K., Tabata, H., Kawai, T., (2001) Appl. Phys. Lett, 79, p. 988
3. Cho, Y.M., Choo, W.K., Kim, H., Ihm, Y.E., (2001) Appl. Phys. Lett, 80, p. 3358
4. Lee, H.J., Jeong, S.Y., Cho, C.R., Park, C.H., (2002) Appl. Phys. Lett, 81, p. 4020
5. Lee, H.-J., Kim, S.-K., Cho, C.R., Kim, S.-J., Jeong, S.-Y., (2005) J. Korean Phys. Soc, 46, p. 34
6. Rode, K., Anane, A., Contuor, J.P., (2003) J. Appl. Phys, 93, p. 7676
7. Saeki, H., Tabata, H., Kawai, T., (2001) Solid State Commun, 120, p. 439
8. Han, S.J., Song, J.W., (2002) Appl. Phys. Lett, 81, p. 4212
9. Song, Y.Y., Park, K.S., Son, D.V., Yu, S.C., Kang, H.J., Shin, S.W., Whang, C.N., Lee, K.W., (2007) J. Korean Phys. Soc, 50, p. 1706
10. Koidl, P., (1977) Phys. Rev. B, 15, p. 2493
11. Gaj, J.A., (1988) Semiconductors and Semimetals, 25, p. 275. , edited by J. K. Furdyna and J. Kossut Academic Press, Boston
12. Kudryavtsev, Y.V., Dubowik, J., Kim, K.W., Lee, G.M., Lee, Y.P., Whang, C.N., (1997) J. Korean Phys. Soc, 31, p. 122